

Transistors

Medium Power Transistor (Motor, Relay drive) (-80V, -4A)

2SB1676

● Features

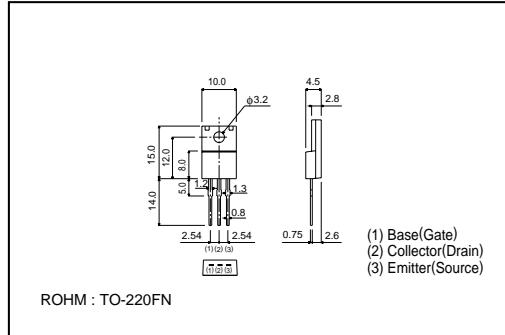
- 1) Darlington connection for a high h_{FE}.
 - 2) Built-in resistor between base and emitter.
 - 3) Built-in damper diode.
 - 4) Complements the 2SD2618.

- **Absolute maximum ratings** ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	-80	V
Collector-emitter voltage	V_{CEO}	-80	V
Emitter-base voltage	V_{EBO}	-7	V
Collector current	I_C	-4	A
	I_{CP}	-6	A(Pulse) *
Collector power dissipation	P_C	2	W(Ta = 25°C)
		30	W(Tc = 25°C)
Junction temperature	T_J	150	°C
Storage temperature	T_{STG}	-55 → +150	°C

* Single pulse, Pw = 100ms

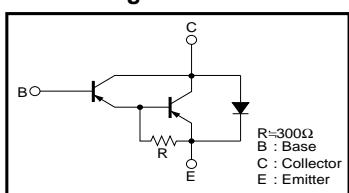
●External dimensions (Units : mm)



● Packaging specifications and hFE

Type	2SB1676
Package	TO-220FN
hFE	1k-10k
Code	-
Basic ordering unit (pieces)	500

● Circuit diagram



● Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BV _{CEO}	-80	-	-	V	I _C = -1mA
Collector-base breakdown voltage	BV _{CBO}	-80	-	-	V	I _C = -50μA
Emitter-base breakdown voltage	BV _{EBO}	-7	-	-	V	I _E = -50μA
Collector cutoff current	I _{CBO}	-	-	-10	μA	V _{CB} = -80V
Emitter cutoff current	I _{EBO}	-	-	-10	μA	V _{EB} = -5V
Collector-emitter saturation voltage	V _{CE(sat)}	-	-	-1.5	V	I _C /I _S = -2A/-4mA
DC current transfer ratio	h _{FE}	1000	-	10000	-	V _{CE} /I _C = -3V/-2A
Transition frequency	f _T	-	20	-	MHz	V _{CE} = -5V , I _E = 0.5A , f = 10MHz
Output capacitance	C _{OB}	-	22	-	pF	V _{CB} = -10V , I _E = 0A , f = 1MHz

*1 Measured using pulse current. *2 Transition frequency of the device.

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